

**Call for papers – Invitation to authors**  
**Special Issue in physica status solidi (a)**  
**Gettering and Defect Engineering in Semiconductor Technology**  
**(GADEST 2019)**

Guest Editors

**Gudrun Kissinger, Dawid Kot, Marvin Zöllner, and Hans Richter**

**Extended Submission Deadline: April 15<sup>th</sup>, 2019** (new acceptance deadline July 31<sup>st</sup>, 2019)

Submission at: <http://www.editorialmanager.com/pssa-journal>

Special category:

**Gettering and Defect Engineering in Semiconductor Technology (GADEST 2019)**

Dear GADEST 2019 presenters,

Related to the *International Conference on Gettering and Defect Engineering in Semiconductor Technology* it is once again planned to publish a special issue in pss (a) – applications and materials science. In collaboration between the Guest Editor and the pss Editorial Office we cordially invite you to submit a **Feature Article** (topical review, for invited speakers) or **Original Paper** manuscript based on, or related to, your presentation.

**The publication will be a regular special issue, not a conference proceedings.** Articles must fulfil the typical standards and requirements of the journal. Acceptance of a contribution for presentation at the conference does not automatically include publication in the Special Issue. The physica status solidi journals are designed to reach a broad audience in the field of condensed matter and materials physics. pss is one of the largest and well-established publication platforms in solid state physics with more than 1500 articles per year – now over 55 years in business – and is widely accessible as part of many institutional site licenses, evidenced by close to one million article downloads annually.

All submitted manuscripts will undergo **peer review**. According to the editorial policy of pss, two positive recommendations by independent referees are a prerequisite of acceptance. Peer review and publication occur on individual manuscript basis. Published in Wiley Online Library **Early View** a few weeks after acceptance, your article is citable immediately; hence there is **no waiting for the remainder of the contributions**. When all articles are complete, they will be assigned to the monthly issue of pss (a). *Please note that we cannot guarantee to include your article in the Special Issue if we receive it after the above given deadline.*

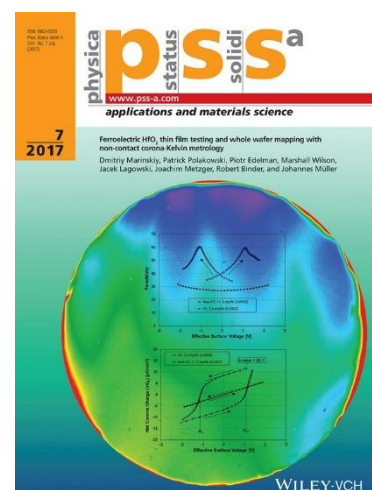
Please refer to the guidelines received from the symposium organizers and the author instructions available on our homepage <http://www.pss-a.com> -> **Author Guidelines** (including Word template and LaTeX style files and the link to **online submission** through Editorial Manager).

Please **mention the GADEST 2019 special issue** in your cover letter and select the appropriate section/category Gettering and Defect Engineering in Semiconductor Technology (GADEST 2019) to expedite handling.

We look forward to receiving your contributions!

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pss Editorial Office: Marc Zastrow, Stefan Hildebrandt [pssa@wiley-vch.de](mailto:pssa@wiley-vch.de)  
Journal homepage: [www.pss-a.com](http://www.pss-a.com)  
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## Information on submissions:

**Original Papers** expose original and previously unpublished work of general interest to the community. Manuscripts do not have a strict length limit (typical lengths vary from 6 to 10 journal pages). Articles must fulfil the standards and requirements of the journal. Main criteria for consideration by pss (a) are:

- Relevance and novelty of the topic match expectations for a regular journal paper.
- The general quality of the manuscript and the amount of information provided is appropriate for an international journal. Serial or incremental, pure self-referential and lab-report-style work is discouraged.
- Main results have not yet been published (also not in conference proceedings) and are not under consideration for publication elsewhere.
- Please make sure not to copy content from (even your own) previous publications. All submitted manuscripts will be processed through the [iThenticate](#) text verification system.

**Feature Articles** should provide an overview of a current topic in the format of a topical review of about 10–12 (max. 15) journal pages. Due to this length restriction, a complete bibliographic overview on the existing literature cannot be expected, but referencing should be well-balanced. The manuscript should represent a snapshot of most recent progress, the state of research and particularly relevant aspects, with focus on the highlights and possibly open or controversially discussed questions. They are intended to inform an audience not immediately familiar with the specific topic. Original, previously unpublished results may also be included to a certain extent.

**Benefits** for pss authors include:

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C. M. and S. K. Estreicher  
Phys. Status Solidi A **2017**, 214, 1700204. (DOI [10.1002/pssa.201700204](https://doi.org/10.1002/pssa.201700204))

